



DC Input
Photo-Darlington Optocoupler



DESCRIPTION

The SDD400 consists of a Photo Darlington transistor optically coupled to a light emitting diode. Optical coupling between the input LED and output Photo Darlington allows for high isolation levels while maintaining low-level DC signal control capability. The SDD400 provides an optically isolated method of controlling many interface applications such as telecommunications, industrial control and instrumentation circuitry.

FEATURES

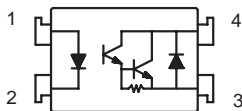
- High Load Voltage ($V_{ceo} = 300V$ MIN)
- High current transfer ratio (600-9000%)
- High input-to-output isolation package (5000 Vrms)
- Compact 4pin DIP package
- RoHS / Pb Free / REACH Compliant device

OPTIONS/SUFFIXES*

- -H .04" (10.16mm) lead spacing (VDE0884)
- -S Surface Mount Option
- -TR Tape and Reel Option

NOTE: Suffixes listed above are not included in marking on device for part number identification.

SCHEMATIC DIAGRAM



1. Anode
2. Cathode
3. Emitter
4. Collector

APPLICATIONS

- Home Appliances
- Office Automation Equipment
- Telecom / Datacom
- Power supplies
- Fax / Modems

ABSOLUTE MAXIMUM RATINGS*

PARAMETER	UNIT	MIN	TYP	MAX
Storage Temperature	°C	-55		125
Operating Temperature	°C	-40		100
Continuous Forward Current	mA			50
Peak Forward Current	A			1
Reverse Voltage	V			6
Output Power Dissipation	mW			200

*The values indicated are absolute stress ratings. Functional operation of the device is not implied at these or any conditions in excess of those defined in electrical characteristics section of this document. Exposure to Absolute Ratings may cause permanent damage to the device and may adversely affect reliability.

APPROVALS

- UL and C-UL Approved, File #E201932
- VDE Approved, License # 40011227

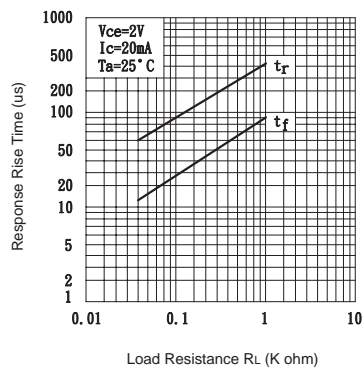
ELECTRICAL CHARACTERISTICS - 25°C

PARAMETER	UNIT	MIN	TYP	MAX	TEST CONDITIONS
INPUT SPECIFICATIONS					
LED Forward Voltage	V		1.2	1.4	If = 20mA
Peak Forward Voltage	V			3.5	Ifm = 0.5A
Reverse Current	μ A			10	Vr=4V
Terminal Capacitance	p F		30		V=0, f=1kHz
OUTPUT SPECIFICATIONS					
Collector-Emitter Breakdown Voltage	V	300			Ic = 10uA
Emitter-Collector Voltage	V	0.1			Ie = 10uA
Dark Current	μ A			1	Vce = 200V, If=0
Floating Capacitance	p F		0.6	1	Vce = 0V, f=1.0MHz
Saturation Voltage (Collector - Emitter)	V			1.5	If = 20mA, Ic = 5mA
Current Transfer Ratio	%	600		9000	If = 1mA, Vce = 2V
Rise Time	μ s		60	300	Ic = 20mA, Vce = 2V, RL = 100 ohms
Fall Time	μ s		50	250	Ic = 20mA, Vce = 2V, RL = 100 ohms
COUPLED SPECIFICATIONS					
Isolation Voltage	V	5000			T = 1 minute
Isolation Resistance	G Ω	50			DC 500V
Cut off Frequency	k H z		7		Ic = 2mA, Vcc = 5V, RL = 100 ohms
CTR CLASSIFICATION					
-A	%	600		2000	
-B	%	1500		4000	
-C	%	3000		6000	
-D	%	5000		9000	
-E	%	600		9000	

PERFORMANCE DATA

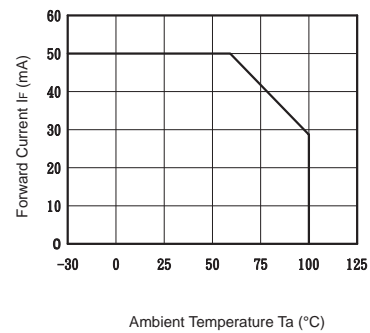
SDD400

Response Time vs. Load Resistance
N = 100, Ambient Temperature = 25°C



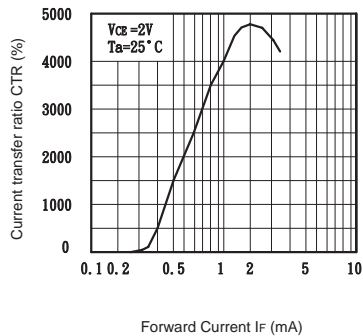
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Forward Current vs. Ambient Temperature
N = 100



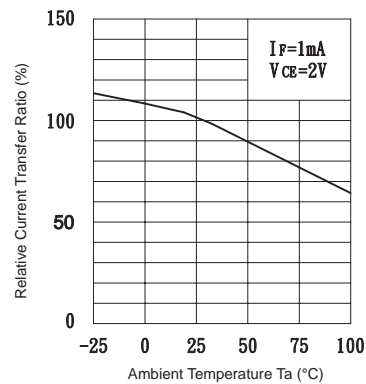
SDD400

Current Transfer Ratio vs. Forward Current
N = 100, Ambient Temperature = 25°C



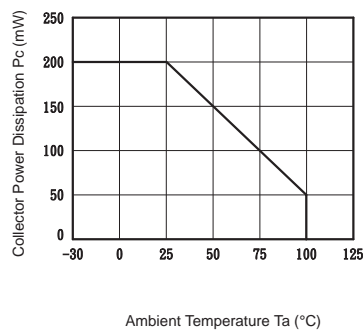
SDD400

Relative Current Transfer Ratio vs. Ambient Temperature
N = 100



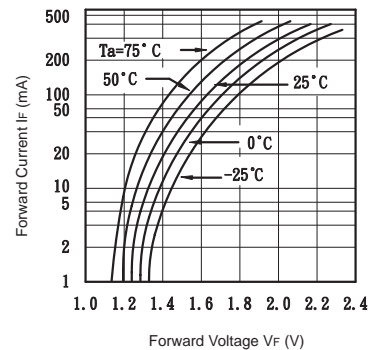
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Collector Power Dissipation vs. Ambient Temperature
N = 100



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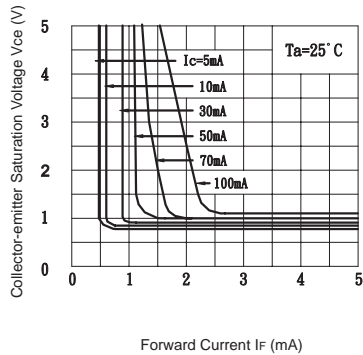
Forward Current vs. Forward Voltage
N = 100, Ambient Temperature = 25°C



PERFORMANCE DATA

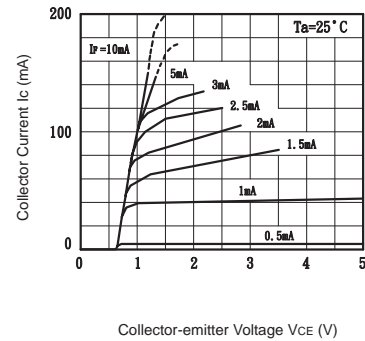
SDD400

Collector - Emitter Saturation Voltage vs. Forward Current
N = 100, Ambient Temperature = 25°C



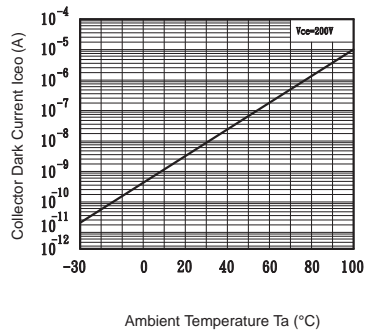
SDD400

Collector Current vs. Collector-Emitter Voltage
N = 100, Ambient Temperature = 25°C



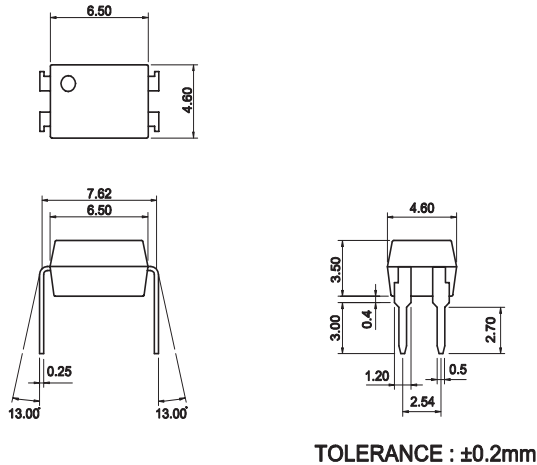
SDD400

Collector Dark Current vs. Ambient Temperature
N = 100

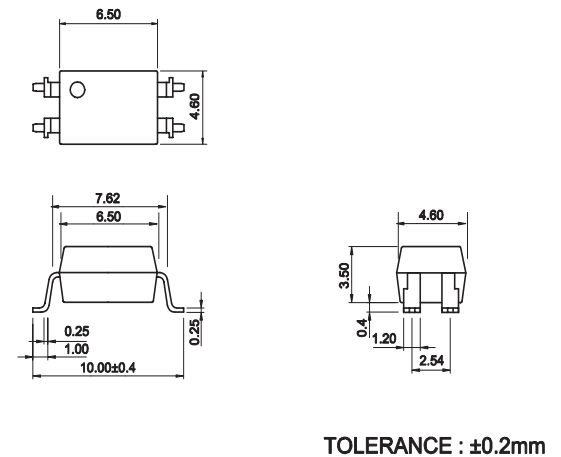


MECHANICAL DIMENSIONS

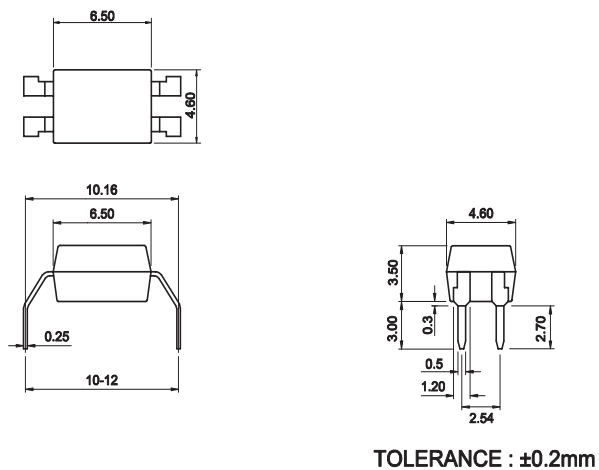
4 PIN DUAL INLINE PACKAGE (SDD400)



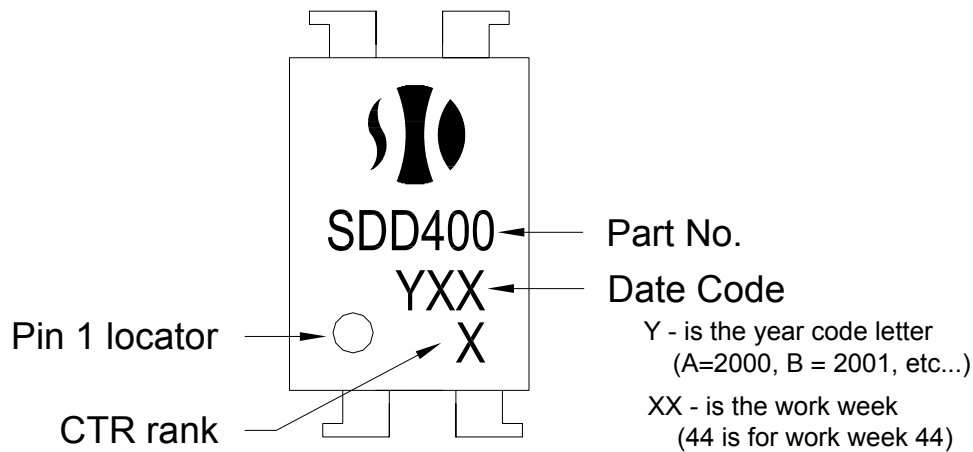
4 PIN SURFACE MOUNT DEVICE (SDD400-S)



4 PIN -H TYPE WITH 0.4" LEAD SPACING (SDD400-H)



MARKING INSTRUCTIONS



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